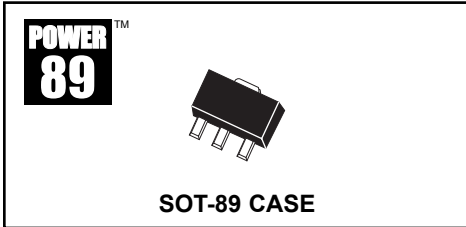


**CXT3150**  
**SURFACE MOUNT**  
**NPN SILICON POWER TRANSISTOR**



# Central<sup>TM</sup>

**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CXT3150 type is a NPN Silicon Power Transistor manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for high current, high gain, fast switching applications.

**MARKING CODE: FULL PART NUMBER**

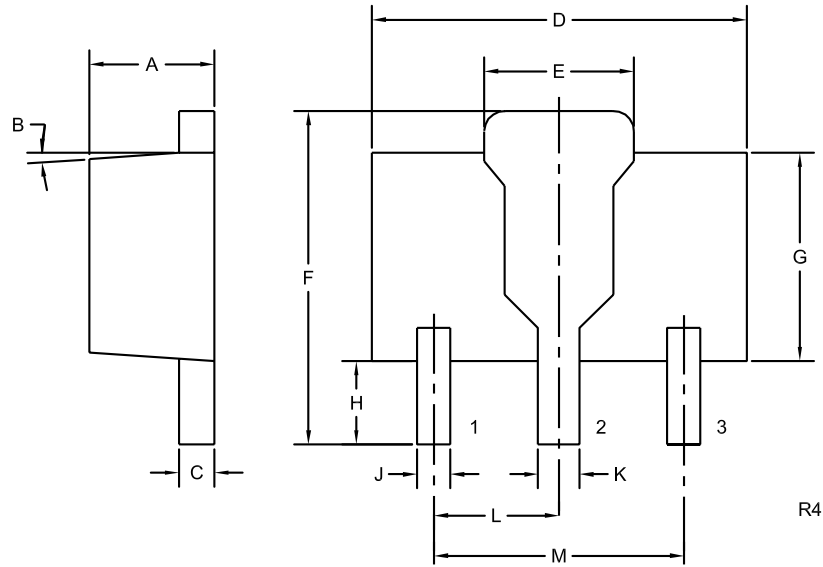
**MAXIMUM RATINGS:** ( $T_A=25^{\circ}\text{C}$ )

	<b>SYMBOL</b>		<b>UNITS</b>
Collector-Base Voltage	$V_{CBO}$	50	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	7.0	V
Collector Current	$I_C$	5.0	A
Base Current	$I_B$	1.0	A
Power Dissipation	$P_D$	1.2	W
Operating and Storage			
Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance	$\Theta_{JA}$	104	$^{\circ}\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNITS</b>
$I_{CBO}$	$V_{CB}=50\text{V}$			1.0	$\mu\text{A}$
$I_{EBO}$	$V_{EB}=7.0\text{V}$			1.0	$\mu\text{A}$
$BV_{CEO}$	$I_C=10\text{mA}$	25			V
$V_{CE(SAT)}$	$I_C=3.0\text{A}, I_B=150\text{mA}$			0.35	V
$V_{CE(SAT)}$	$I_C=4.0\text{A}, I_B=200\text{mA}$			0.50	V
$V_{BE(SAT)}$	$I_C=3.0\text{A}, I_B=150\text{mA}$			1.10	V
$V_{BE(SAT)}$	$I_C=4.0\text{A}, I_B=200\text{mA}$			1.40	V
$h_{FE}$	$V_{CE}=2.0\text{V}, I_C=500\text{mA}$	250		550	
$h_{FE}$	$V_{CE}=2.0\text{V}, I_C=2.0\text{A}$	150			
$h_{FE}$	$V_{CE}=2.0\text{V}, I_C=5.0\text{A}$	50			
$f_T$	$V_{CE}=6.0\text{V}, I_C=50\text{mA}, f=200\text{MHz}$		150		MHz
$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$			50	pF

**SOT-89 CASE - MECHANICAL OUTLINE**



**LEAD CODE:**

- 1) EMITTER
- 2) COLLECTOR
- 3) BASE

**MARKING CODE:  
FULL PART NUMBER**

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.067	1.40	1.70
B	4°		4°	
C	0.014	0.018	0.35	0.46
D	0.173	0.185	4.40	4.70
E	0.064	0.074	1.62	1.87
F	0.146	0.177	3.70	4.50
G	0.090	0.106	2.29	2.70
H	0.028	0.051	0.70	1.30
J	0.014	0.019	0.36	0.48
K	0.017	0.023	0.44	0.58
L	0.059		1.50	
M	0.118		3.00	

SOT-89 (REV: R4)

R4 (20-May 2004)